TERMINATION CHIP 30 WATT





PART SERIES: 82A3019F **DATA SHEET**

SHEET 1 OF 2 Dwg 82A3019F

EN 13-3450

FEATURES

Direct Attached

APPLICATIONS

Mobile Networks Wide Band Operation High Power Broadcast

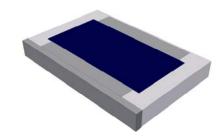
High Power Amplifiers

Low VSWR Isolators Military Easy Installation

Instrumentation



EMC Technology offers the widest selection of chip terminations worldwide. Chip components are offered in both thick and thin film resistive material and available in Alumina, Aluminum Nitride, Beryllium Oxide and CVD Diamond.



ORDERING INFORMATION

Part Identifier: 82A3019F

SPECIFICATIONS

1.0 ELECTRICAL

Nominal Impedance: 50 ohms Frequency Range: DC - 1.0 GHz VSWR: 1.50:1 Max

Input Power CW: 30 Watts @ 100°C heat sink, derated linearly to zero power and 150°C

Peak Power: 300 Watts (based on 10us pulse width and 1% duty cycle)

DC Resistance: 50 Ω ±5%

2.0 ENVIRONMENTAL

-55°C to +150°C Operating Temperature: Non-operating Temperature: -65°C to +150°C +/-200 PPM / ° C max Temperature Coefficient:

3.0 MARKING

Unit Marking: No Marking

4.0 QUALITY ASSURANCE

Visual and Mechanical Inspection: Per 824W107

100% DC Resistance Check DC Resistance Check:

Data Retention: Standard

5.0 PACKAGING

Standard Packaging: Tape and Reel

smiths microwave Form 423F103 Rev-

Cage Codes: 24602 / 2Y194

Specifications are Subject to Change Without Notice

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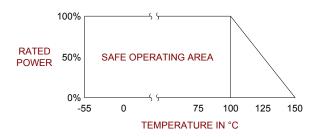
DATA SHEET PART SERIES: 82A3019F

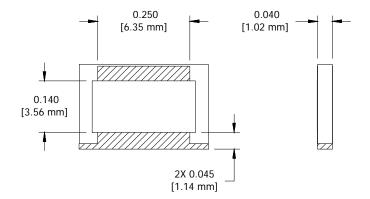
SHEET 2 OF 2 Dwg 82A3019F

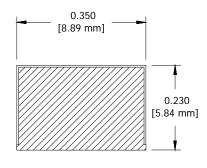
6.0 MECHANICAL

Substrate Material: Beryllium Oxide Thin Film Resistive Film: Terminal Material: Silver Plated

Metric Dimensions: Provided for reference only







Unless Otherwise Specified: TOLERANCE: $X.XX = \pm 0.02$ $X.XXX = \pm 0.010$

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